

Dual Schmitt Trigger Buffer

Check for Samples: SN74LVC2G17

FEATURES

- Available in the Texas Instruments NanoFree[™] Package
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 5.4 ns at 3.3 V
- Low Power Consumption, 10-μA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2 V at V_{CC} = 3.3 V, T_A = 25°C
- I_{off} Supports Live Insertion, Partial-Power-Down Mode Operation and Back Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 1000-V Charged-Device Model (C101)

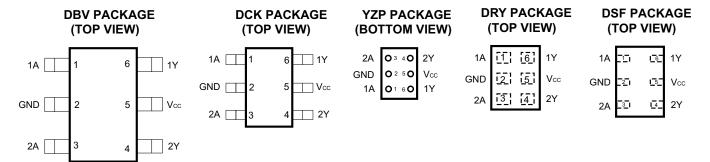
DESCRIPTION

This dual Schmitt-trigger buffer is designed for 1.65-V to 5.5-V $V_{\rm CC}$ operation.

The SN74LVC2G17 contains two buffers and performs the Boolean function Y = A. The device functions as two independent buffers, but because of Schmitt action, it may have different input threshold levels for positive-going (V_{T-}) and negative-going (V_{T-}) signals.

NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using $I_{\rm off}$. The $I_{\rm off}$ circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





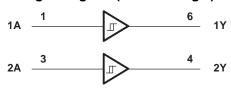
This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Function Table (Each Inverter)

INPUT A	OUTPUT Y
Н	Н
L	L

Logic Diagram (Positive Logic)



Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range (2)		-0.5	6.5	V
Vo	Voltage range applied to any output in	the high-impedance or power-off state (2)	-0.5	6.5	V
Vo	Voltage range applied to any output in	the high or low state (2) (3)	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
l _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current	·		±50	mA
	Continuous current through V _{CC} or GN	D		±100	mA
		DBV package		165	
		DCK package		259	
θ_{JA}	Package thermal impedance (4)	YZP package		123	°C/W
		DRY package		234	
		DSF package		300	
TJ	Junction temperature under bias			150	°C
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CC} is provided in the recommended operating conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

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Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT	
V _{CC}	Supply voltage	Operating	1.65	5.5	V	
VI	Input voltage	•	0	5.5	V	
Vo	Output voltage		0	V_{CC}	V	
		V _{CC} = 1.65 V		-4		
		V _{CC} = 2.3 V		-8		
I _{OH}	High-level output current	V 0V		-16	mA	
		$V_{CC} = 3 V$		-24		
		V _{CC} = 4.5 V		-32		
		V _{CC} = 1.65 V		4	·	
		V _{CC} = 2.3 V		8		
I_{OL}	Low-level output current	V 0V		16	mA	
		V _{CC} = 3 V		24		
		V _{CC} = 4.5 V		32		
T _A	Operating free-air temperature		-40	125	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Product Folder Links: SN74LVC2G17



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	-40	0°C to 85°C	-40	°C to 125°C	UNIT
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾ MAX	MIN	TYP ⁽¹⁾ MAX	UNII
		1.65 V	0.7	1.4	0.7	1.4	
V_{T+}		2.3 V	1.0	1.7	1.0	1.7	
Positive-going input		3 V	1.3	2.0	1.3	2.0	V
threshold voltage		4.5 V	1.9	3.1	1.9	3.1	
		5.5 V	2.2	3.7	2.2	3.7	
		1.65 V	0.3	0.7	0.3	0.7	
V _T _		2.3 V	0.4	1	0.4	1.0	
Negative-going input		3 V	0.8	1.3	0.8	1.3	V
threshold voltage		4.5 V	1.1	2	1.1	2.0	
		5.5 V	1.4	2.5	1.4	2.5	
		1.65 V	0.3	0.8	0.3	0.8	
ΔV_{T}		2.3 V	0.4	0.9	0.35	0.9	
Hysteresis		3 V	0.4	1.1	0.4	1.1	V
$(V_{T+} - V_{T-})$		4.5 V	0.6	1.3	0.6	1.3	
		5.5 V	0.7	1.4	0.7	1.4	
	I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} – 0.1		V _{CC} – 0.1		
	I _{OH} = -4 mA	1.65 V	1.2		1.2		1
V_{OH}	I _{OH} = -8 mA	2.3 V	1.9		1.9		V
OH	I _{OH} = -16 mA	0.1/	2.4		2.4		
	I _{OH} = -24 mA	3 V	2.3		2.3		
	I _{OH} = -32 mA	4.5 V	3.8		3.8		
	Ι _{ΟL} = 100 μΑ	1.65 V to 5.5 V		0.1		0.1	
	I _{OL} = 4 mA	1.65 V		0.45		0.45	
V _{OL}	I _{OL} = 8 mA	2.3 V		0.3		0.3	V
OL .	I _{OL} = 16 mA	214		0.4		0.4	
	I _{OL} = 24 mA	3 V		0.55		0.55	
	I _{OL} = 32 mA	4.5 V		0.55		0.55	
I _I A input	V _I = 5.5 V or GND	0 to 5.5 V		±5		±5	μA
l _{off}	V_1 or $V_0 = 5.5 \text{ V}$	0		±10		±10	μA
I _{CC}	$V_1 = 5.5 \text{ V or GND}, \qquad I_0 = 0$	1.65 V to 5.5 V		10		10	μA
ΔI _{CC}	One input at V_{CC} – 0.6 Other inputs at V_{CC} or V, GND	3 V to 5.5 V		500		500	μA
C _i	$V_I = V_{CC}$ or GND	3.3 V		4		4	pF

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

	FROM (INPUT)		SN74LVC2G17 -40°C to 85°C								
PARAMETER		TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	Υ	3.9	9.3	1.9	5.7	2.2	5.4	1.5	4.3	ns

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Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		PARAMETER						SN74LV -40°C to					
	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT	
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
ſ	t _{pd}	Α	Υ	3.9	9.8	1.9	6.2	2.2	5.9	1.5	4.8	ns	

Operating Characteristics

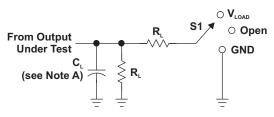
 $T_A = 25$ °C

	PARAMETER	TEST CONDITIONS	$V_{CC} = 1.8 \text{ V}$	$V_{CC} = 2.5 \text{ V}$	$V_{CC} = 3.3 \text{ V}$	UNIT		
	PARAMETER	TEST CONDITIONS	TYP	TYP	TYP	TYP	UNII	
С	Power dissipation capacitance	f = 10 MHz	17	18	19	21	pF	

Product Folder Links: SN74LVC2G17



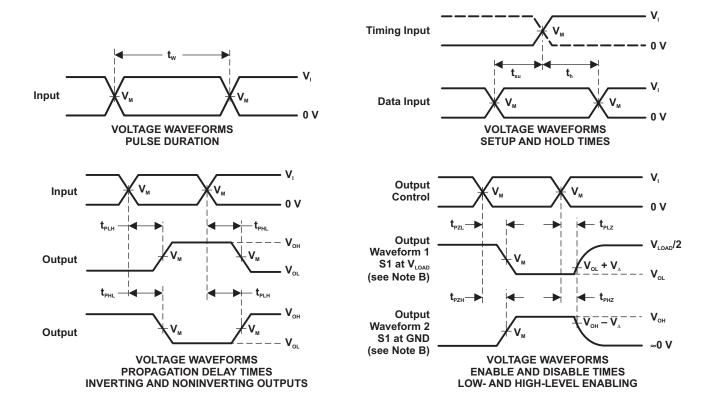
Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL}	Open
$t_{_{\mathrm{PLZ}}}/t_{_{\mathrm{PZL}}}$	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

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V _{cc}	V _{cc} V _i	t,/t,	V _M	V _{LOAD}	C _L	R _⊾	V _A
1.8 V ± 0.15 V	V _{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	30 pF	1 k Ω	0.15 V
$2.5~\textrm{V}~\pm~0.2~\textrm{V}$	V _{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	30 pF	500 Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V ± 0.5 V	V _{cc}	≤2.5 ns	V _{cc} /2	2 × V _{cc}	50 pF	500 Ω	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{o} = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. $t_{\mbox{\tiny PLZ}}$ and $\dot{t}_{\mbox{\tiny PHZ}}$ are the same as $t_{\mbox{\tiny dis}}.$
- F. $t_{\mbox{\tiny PZL}}$ and $t_{\mbox{\tiny PZH}}$ are the same as $t_{\mbox{\tiny en}}.$
- G. $t_{\mbox{\tiny PLH}}$ and $t_{\mbox{\tiny PHL}}$ are the same as $t_{\mbox{\tiny pd}}.$
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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REVISION HISTORY

Changes from Revision J (June 2012) to Revision K	Page
Updated pin out graphic.	1
Changes from Revision K (July 2012) to Revision L	Page
Updated document to new TI datasheet format - no specification changes	1
Changes from Revision L (September 2013) to Revision M	Page
Updated document formatting.	1
Updated operating temperature range.	3





14-Sep-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins			Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LVC2G17DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C172 ~ C175 ~ C17F ~ C17K ~ C17R)	Samples
SN74LVC2G17DBVRE4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C172 ~ C175 ~ C17F ~ C17K ~ C17R)	Samples
SN74LVC2G17DBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C172 ~ C175 ~ C17F ~ C17K ~ C17R)	Samples
SN74LVC2G17DBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C172 ~ C175 ~ C17F ~ C17K ~ C17R)	Samples
SN74LVC2G17DCK3	ACTIVE	SC70	DCK	6	3000	Pb-Free (RoHS)	CU SNBI	Level-1-260C-UNLIM	-40 to 85	(C7F ~ C7Z)	Samples
SN74LVC2G17DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C75 ~ C7F ~ C7K ~ C7R)	Samples
SN74LVC2G17DCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C75 ~ C7F ~ C7K ~ C7R)	Samples
SN74LVC2G17DCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C75 ~ C7F ~ C7K ~ C7R)	Samples
SN74LVC2G17DCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C75 ~ C7F ~ C7K ~ C7R)	Samples
SN74LVC2G17DCKTE4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C75 ~ C7F ~ C7K ~ C7R)	Samples
SN74LVC2G17DCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C75 ~ C7F ~ C7K ~ C7R)	Samples
SN74LVC2G17DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C7	Samples
SN74LVC2G17DSF2	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C7	Samples
SN74LVC2G17DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C7	Samples
SN74LVC2G17YZPR	ACTIVE	DSBGA	YZP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(C77 ~ C7N)	Samples

PACKAGE OPTION ADDENDUM



14-Sep-2014

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC2G17:

Automotive: SN74LVC2G17-Q1

■ Enhanced Product: SN74LVC2G17-EP





14-Sep-2014

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G17DBVR	SOT-23	DBV	6	3000	178.0	9.2	3.3	3.2	1.55	4.0	8.0	Q3
SN74LVC2G17DBVR	SOT-23	DBV	6	3000	180.0	9.2	3.17	3.23	1.37	4.0	8.0	Q3
SN74LVC2G17DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC2G17DBVT	SOT-23	DBV	6	250	180.0	9.2	3.17	3.23	1.37	4.0	8.0	Q3
SN74LVC2G17DBVT	SOT-23	DBV	6	250	178.0	9.2	3.3	3.2	1.55	4.0	8.0	Q3
SN74LVC2G17DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC2G17DCKR	SC70	DCK	6	3000	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74LVC2G17DCKT	SC70	DCK	6	250	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74LVC2G17DCKT	SC70	DCK	6	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC2G17DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC2G17DSF2	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q3
SN74LVC2G17DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC2G17YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

All dimensions are nominal										
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)			
SN74LVC2G17DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0			
SN74LVC2G17DBVR	SOT-23	DBV	6	3000	205.0	200.0	33.0			
SN74LVC2G17DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0			
SN74LVC2G17DBVT	SOT-23	DBV	6	250	205.0	200.0	33.0			
SN74LVC2G17DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0			
SN74LVC2G17DCKR	SC70	DCK	6	3000	180.0	180.0	18.0			
SN74LVC2G17DCKR	SC70	DCK	6	3000	205.0	200.0	33.0			
SN74LVC2G17DCKT	SC70	DCK	6	250	205.0	200.0	33.0			
SN74LVC2G17DCKT	SC70	DCK	6	250	180.0	180.0	18.0			
SN74LVC2G17DRYR	SON	DRY	6	5000	184.0	184.0	19.0			
SN74LVC2G17DSF2	SON	DSF	6	5000	184.0	184.0	19.0			
SN74LVC2G17DSFR	SON	DSF	6	5000	184.0	184.0	19.0			
SN74LVC2G17YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0			

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



DCK (R-PDSO-G6)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. SON (Small Outline No-Lead) package configuration.
- The exposed lead frame feature on side of package may or may not be present due to alternative lead frame designs.
- E. This package complies to JEDEC MO-287 variation UFAD.
- $frac{f}{K}$ See the additional figure in the Product Data Sheet for details regarding the pin 1 identifier shape.



DRY (R-PUSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
 C. SON (Small Outline No-Lead) package configuration.
 D. This package complies to JEDEC MO-287 variation X2AAF.





PLASTIC SMALL OUTLINE NO-LEAD



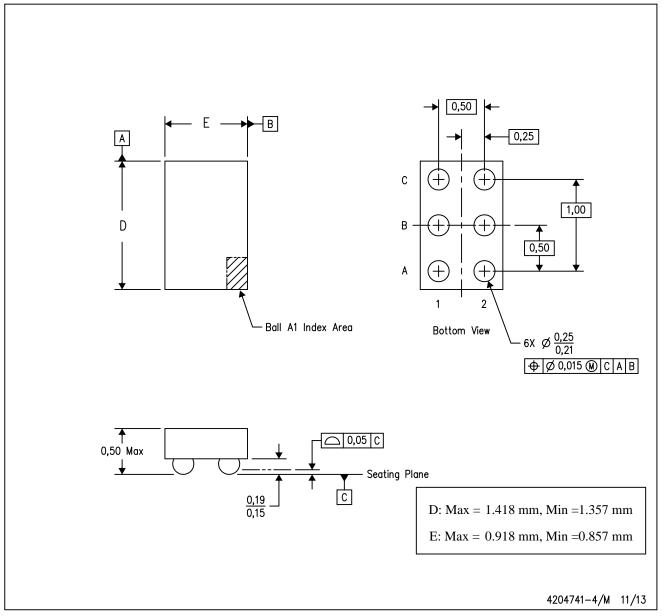
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



YZP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree \mathbf{M} package configuration.

NanoFree is a trademark of Texas Instruments.



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